

IQ Detection IC for Digital Satellite Broadcast Tuner

Description

The CXA3038N is an IC for IQ-detection of DSS, DVB, and other digital satellite broadcast QPSK modulation signals in the 480 MHz band. It consists of an AGC amplifier circuit, oscillator circuit, phase shifter circuit, and phase comparison circuit. In addition, the chip has a PLL circuit for frequency control and built-in control data. It realizes high-accuracy oscillator frequencies through use of a low-cost LC resonance circuit.

Features

- Built-in PLL for controlling oscillator frequency.
- Oscillator frequency based at 479.5 MHz is adjustable in ± 4 steps of 50 kHz using the voltage of the control pin.
- Reference OSC allows switching to 4 MHz or 10 MHz.
- Built-in output buffer for reference OSC.
- Low-impedance IQ output.
- AGC gain variation 35 dB.

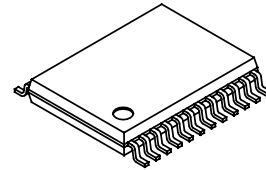
Applications

Digital satellite broadcast tuner

Structure

Bipolar silicon monolithic IC

24 pin SSOP (Plastic)

**Absolute Maximum Ratings** (Ta=25 °C)

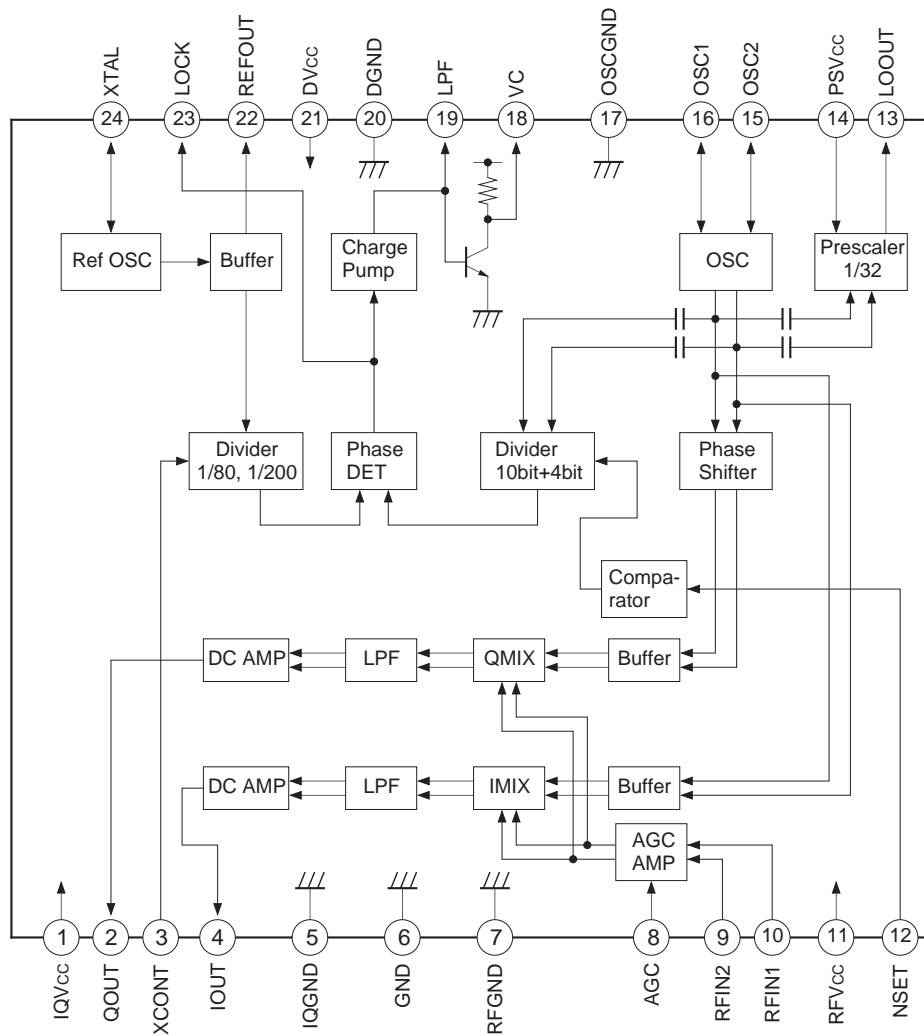
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|-----------------------|------------------|-------------|----|
| • Supply voltage | V _{cc} | -0.3 to 5.5 | V |
| • Storage temperature | T _{stg} | -55 to +150 | °C |

Operating Conditions

- | | | | |
|-------------------------|------------------|--------------|----|
| • Supply voltage | V _{cc} | 4.75 to 5.30 | V |
| • Operating temperature | T _{opr} | -25 to +75 | °C |

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Block Diagram and Pin Configuration



Pin Description

Pin No.	Symbol	Typical pin voltage	Equivalent circuit	Description
1	IQVcc	5 V		IQ output circuit Vcc.
2	QOUT	2.7 V		Q output.
3	XCONT	Open or 5 V when using 4 MHz crystal ; 0 V when using 10 MHz crystal.		Switching pin for reference divider frequency-division ratio. This is set to 80 frequency divisions when open or connected to Vcc; 200 frequency divisions when connected to GND.
4	IOUT	2.7 V		I output.
5	IQGND	0 V		IQ output circuit GND.
6	GND	0 V		GND.
7	RF GND	0 V		RF circuit (AGCAmp, MIXER) GND.
8	AGC	0 to 4 V		AGCAmp gain adjustment.

Pin No.	Symbol	Typical pin voltage	Equivalent circuit	Description
9	RFIN2	2.1 V		RF signal inputs.
10	RFIN1	2.1 V		
11	RFV _{cc}	5 V		RF circuit (AGCAmp, MIXER, OSC) V _{cc} .
12	NSET	1.6 V		OSC frequency fine-adjustment. The oscillator frequency based at 479.5 MHz is adjustable in ± 4 steps of 50 kHz by applying a voltage of 0 to 5 V.
13	LOOUT	4 V		Output for OSC frequency signal divided into 32 frequency divisions.
14	PSV _{cc}	5 V		V _{cc} for 32 frequency division circuit. This is set to open when activating the built-in PLL.
15	OSC2	3.7 V		OSC pins. These pins connect the varicap diode and coil resonance circuit.
16	OSC1	3.7 V		
17	OSCGND	0 V		OSC circuit and phase shifter circuit GND.

Pin No.	Symbol	Typical pin voltage	Equivalent circuit	Description
18	VC	0.3 V to 5 V		Voltage output for varicap diode making up the VCO.
19	LPF	1.8 V to 3.7 V		Phase comparison output. This pin connects the loop filter.
20	DGND	0 V		PLL circuit GND.
21	DVcc	5 V		PLL circuit Vcc.
22	REFOUT	4.1 V		REFOSC output.
23	LOCK	0.01 V when unlocked; 3.2 V when locked		PLL lock/unlock monitor.
24	XTAL	4.4 V		Crystal connection.

Electrical Characteristics

Circuit current (Ta=25 °C, Vcc=5 V, see the Electrical Characteristics Measurement Circuit.)

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit
Circuit current A	ICCA	Analog circuit current at no signal. Total current of IQVcc and RFVcc.	41	60	80	mA
Circuit current D	ICCD	PLL circuit current. DVcc current.	2	3.5	5.5	mA
Circuit current L	ICCPs	32-frequency division circuit current at no signal. PSVcc current.	1.1	1.6	2.4	mA

AC Characteristics

(Ta=25 °C, Vcc=5 V, see the Electrical Characteristics Measurement Circuit.)

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit
Input sensitivity	VIN	Iout=10 MHz, 1 Vp-p		-50		dBm
Gain control range	GAGC	Iout=10 MHz, 1 Vp-p, AGC=4 V-0 V	32.5	35	—	dB
Conversion gain	CG	RF=-50 dBm, Iout=10 MHz, AGC=4 V (Full gain)	52	54	57	dB
IQ phase error	BP	RF=-50 dBm, Iout=10 MHz, 1 Vp-p			±4	deg
IQ amplitude error	BV	RF=-50 dBm, Iout=10 MHz, 1 Vp-p			±0.5	dB
Phase frequency error	ΔfBP	RF=-50 dBm, Iout=0 MHz-15 MHz, 1 Vp-p			±0.5	deg
Amplitude frequency error	ΔfBV	RF=-50 dBm, Iout=0 MHz-15 MHz, 1 Vp-p			±0.1	dB
Cut-off frequency	fc	RF=-50 dBm, Iout=From 1 Vp-p to 3 dB down		25		MHz
Maximum Q output	VQMAX	RF=-30 dBm, Qout=10 MHz, AGC=4 V (Full gain)	2.5	3	3.5	Vp-p
Maximum I output	VIMAX	RF=-30 dBm, Iout=10 MHz, AGC=4 V (Full gain)	2.5	3	3.5	Vp-p
Noise figure	NF	Iout=10 MHz, AGC=4 V (Full gain), DSB		9		dB
Third-order intermodulation distortion	IM3	RF1=489.5 MHz, RF2=490.5 MHz, Iout=1 Vp-p		32		dB
Local oscillation phase noise	CN	RF=-50 dBm, Iout=10 MHz, 1Vp-p, 10 kHz offset		-88		dBc/Hz
PLL reference leak	refLK	RF=-50 dBm, Iout=10 MHz, 1Vp-p, 50 kHz S/I		-81		dB
RF pin local oscillation leak	RF _{LK}	AGC=4 V, f=479.5 MHz		-21		dBm
QOUT pin local oscillation leak	QLK1	AGC=4 V, f=479.5 MHz		-34		dBm
	QLK2	AGC=0 V, f=479.5 MHz		-40		
IOUT pin local oscillation leak	ILK1	AGC=4 V, f=479.5 MHz		-34		dBm
	ILK2	AGC=0 V, f=479.5 MHz		-40		
REFout pin local oscillation leak	REFLK	f=479.5 MHz		-34		dBm
RF input admittance	rπ	f=479.5 MHz, AGC=4 V (Full gain)		1.25 k		Ω
	Cπ			1.4		pF

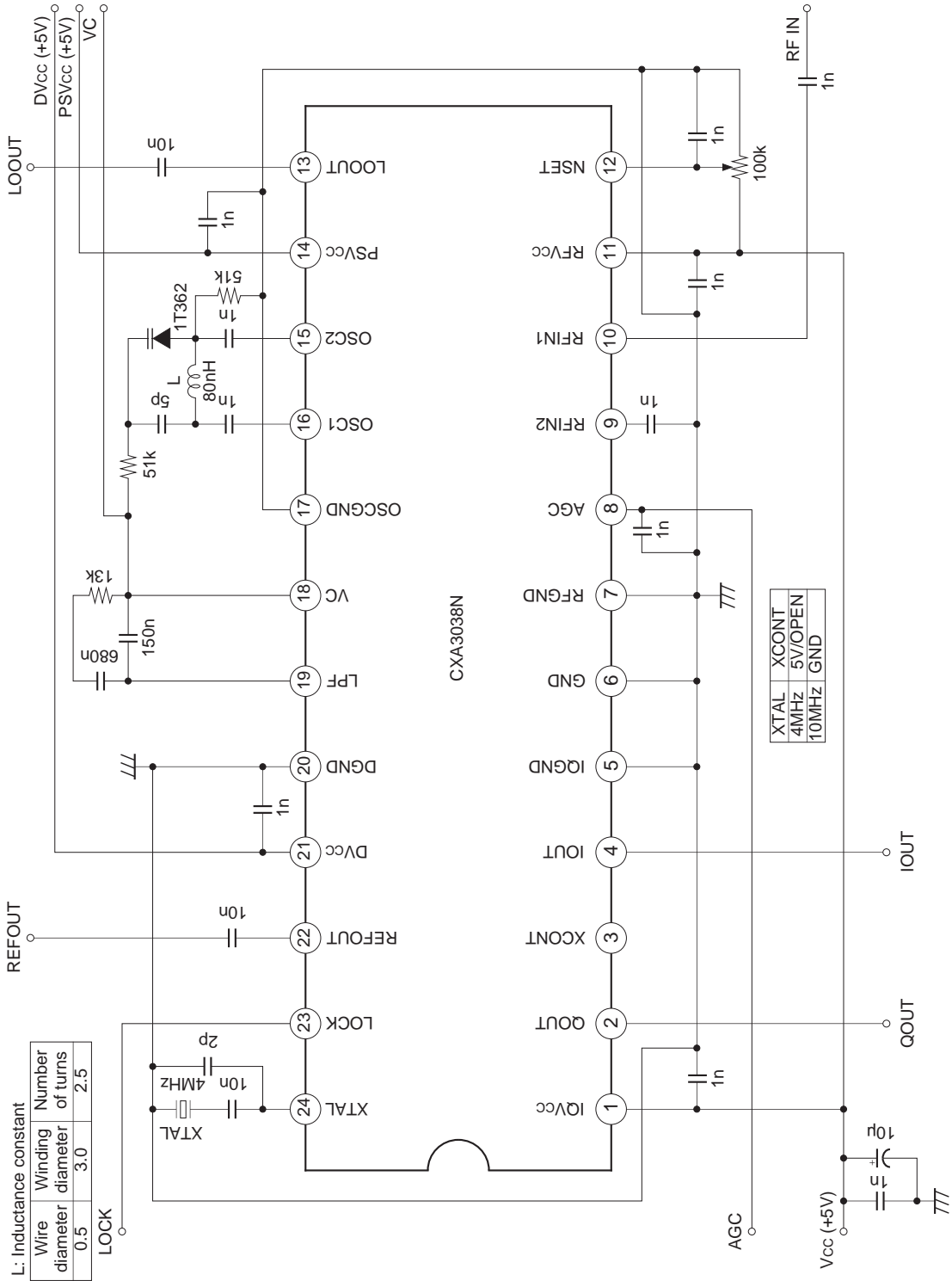
Measured value for untuned inputs.

Noise figure is the direct reading value from the NF meter.

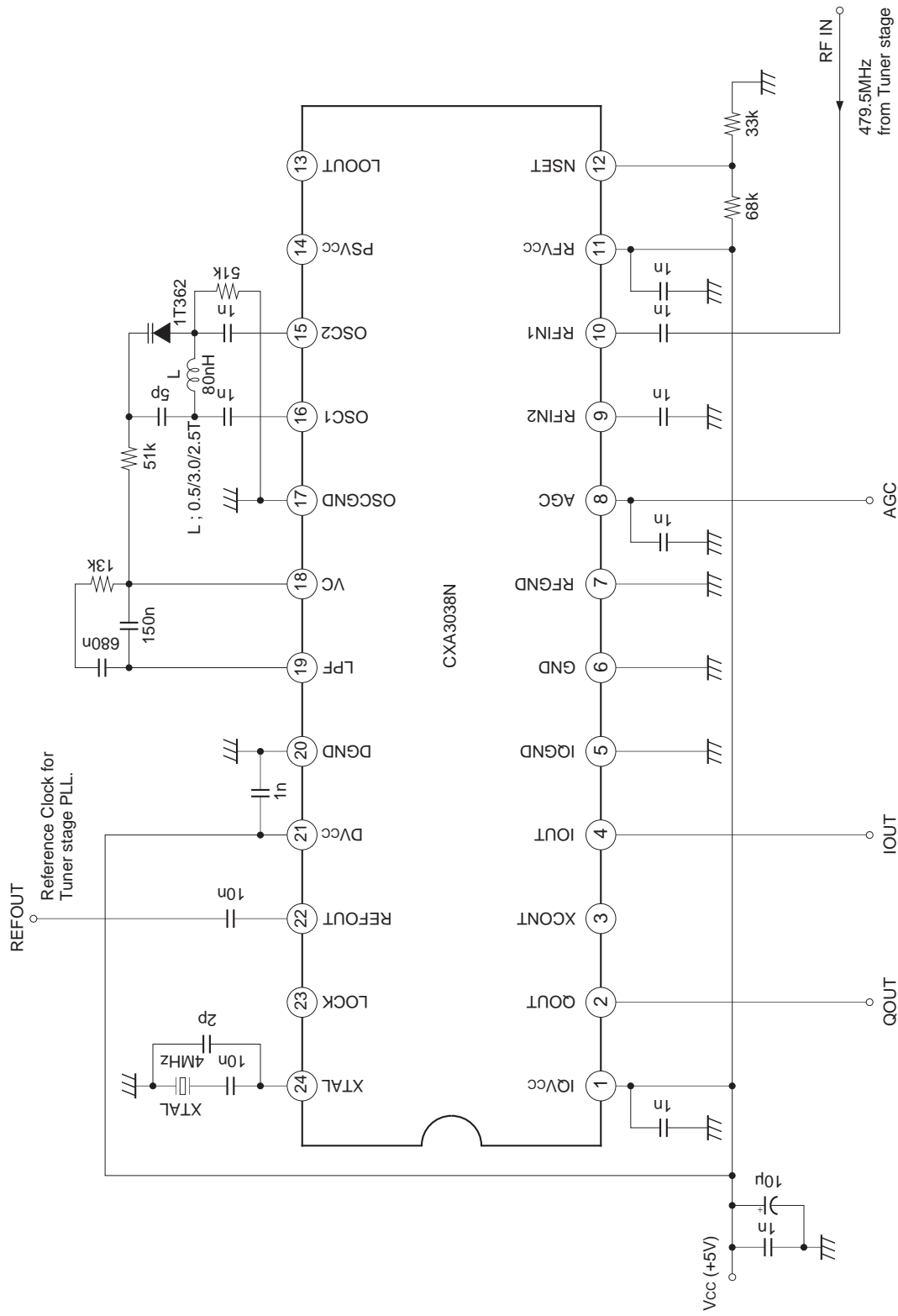
PLL Block (Ta=25 °C, Vcc=5 V, see the Electrical Characteristics Measurement Circuit.)

Item	Symbol	Measurement conditions	Min.	Typ.	Max.	Unit
LPF (charge pump)						
H output current	ILPFH			-50		μA
L output current	ILPFL			50		μA
VC						
Output voltage range	V _{VCH}	XCONT=OPEN, PLL lock	0.3		V _{CC}	V
LOCK						
H output voltage	V _{LH}	XTAL=4 MHz, XCONT=OPEN, PLL lock	2.8	3.2	4.2	V
L output voltage	V _{LL}	XTAL=4 MHz, XCONT=GND, PLL unlock	0	0.01	0.2	V
REFOUT						
Output frequency	f _{REF}	XTAL=4 MHz		4.000		MHz
Output amplitude	V _{REF}	XTAL=4 MHz	230	280	400	mVp-p
LOOUT (32 frequency divisions)						
Output frequency	f _{LO}	OSC=479.5 MHz during PLL lock		14.9844		MHz
Output amplitude	V _{LO}	OSC=479.5 MHz during PLL lock	300	380	500	mVp-p
OSC control						
479.7 MHz control voltage	f+4	NSET=0 V, f ₀ V-f ₀ =f _{Δ4}	0.597 V _{CC}		V _{CC}	V
479.65 MHz control voltage	f+3	NSET=0.4 V, f _{0.4} V-f ₀ =f _{Δ3}	0.517 V _{CC}		0.590 V _{CC}	V
479.6 MHz control voltage	f+2	NSET=0.8 V, f _{0.8} V-f ₀ =f _{Δ2}	0.438 V _{CC}		0.515 V _{CC}	V
479.55 MHz control voltage	f+1	NSET=1.2 V, f _{1.2} V-f ₀ =f _{Δ1}	0.358 V _{CC}		0.436 V _{CC}	V
479.5 MHz control voltage	f ₀	NSET=1.6 V	0.279 V _{CC}		0.356 V _{CC}	V
479.45 MHz control voltage	f-1	NSET=2.0 V, f _{2.0} V-f ₀ =f _{Δ-1}	0.199 V _{CC}		0.277 V _{CC}	V
479.4 MHz control voltage	f-2	NSET=2.4 V, f _{2.4} V-f ₀ =f _{Δ-2}	0.120 V _{CC}		0.197 V _{CC}	V
479.35 MHz control voltage	f-3	NSET=2.6 V, f _{2.6} V-f ₀ =f _{Δ-3}	0.042 V _{CC}		0.118 V _{CC}	V
479.3 MHz control voltage	f-4	NSET=3.2 V, f _{3.2} V-f ₀ =f _{Δ-4}	0		0.04 V _{CC}	V

Electrical Characteristics Measurement Circuit



Application Circuit



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Description of Operation

(See the Electrical Characteristics Measurement Circuit.)

Oscillator circuit

- This is a differential amplification-type oscillator circuit, and it is oscillated by connecting an LC parallel resonance circuit via a coupling capacitance between Pin 15 and Pin 16.
A varicap diode is used as a capacitor for the LC parallel resonance circuit to configure the VCO. Set the L value so that the OSC oscillation frequency is approximately 480 MHz when a voltage of 2.5 V is applied to the varicap diode.
- The oscillator signal is injected into the phase shifter circuit.

Phase shifter circuit

- This is a phase shifter having CR configuration.
This circuit produces two local signals having a 90° phase difference at 479.5 MHz and injects these signals to the IQ mixer circuit.

AGC amplifier circuit

- An IF signal (480 MHz band) from the tuner stage is input to Pins 9 and 10.
This IF signal which is input to Pins 9 and 10 is amplified by the AGC amplifier and injected into the IQ mixer circuit.
- The gain can be adjusted by applying the AGC voltage to Pin 8.
The applied AGC voltage ranges from 0 to 4 V, with the minimum gain at 0 V and the maximum gain at 4 V.

IQ mixer circuit

- This is a double-balance mixer-type circuit consisting of two mixer circuits.
- The IF signal amplified by the AGC amplifier is converted into a base band signal by the local signal.

Low-pass filter circuit

- This is a low-pass filter with a CR configuration.
- The cut-off frequency is set at 25 MHz (−3 dB point).

Output amplifier circuit

- The signal is converted to a base band signal by the I and Q mixer circuits, and the high-frequency component is removed by the low-pass filter. This signal is then amplified by the output amplifier circuit and output to Pin 2 as a Q signal. In the same way, the I signal is output to Pin 4.
- The output is low impedance.

PLL circuit (when Pin 21 is connected to V_{CC})

- A PLL is formed by connecting the anode of the LC parallel resonance circuit varicap diode to the Pin 18 output via a high resistance of approximately 10 k Ω and connecting a loop filter between Pin 18 and Pin 19.
- The PLL circuit consists of a main divider, reference divider, phase comparator, charge pump, and reference oscillator.
- The frequency dividing data is included in the main divider, making external data settings unnecessary.
- The reference frequency has been designed at 50 kHz.
- Fine adjustment of the VCO frequency can be performed by changing the frequency dividing value of the main divider through an applied voltage to Pin 12. This allows adjustment in ± 4 steps at 50 kHz intervals based at 479.5 MHz as shown in the table below.

Pin 12 voltage [V]	Frequency dividing value	VCO oscillation frequency [MHz]
0.597 V _{CC} or more	9594	479.70
0.517V _{CC} to 0.595V _{CC}	9593	479.65
0.438V _{CC} to 0.515V _{CC}	9592	479.60
0.358V _{CC} to 0.436V _{CC}	9591	479.55
0.279V _{CC} to 0.356V _{CC}	9590	479.50
0.199V _{CC} to 0.277V _{CC}	9589	479.45
0.120V _{CC} to 0.197V _{CC}	9588	479.40
0.042V _{CC} to 0.118V _{CC}	9587	479.35
0 to 0.04V _{CC}	9586	479.30

- The reference divider has two types of frequency dividing data, 80 and 200.
- Either 4 MHz or 10 MHz can be selected for the crystal oscillator. When using the 4 MHz crystal oscillator, opening Pin 3 will select a frequency dividing value of 80 for the reference divider, and the reference frequency will become 50 kHz.

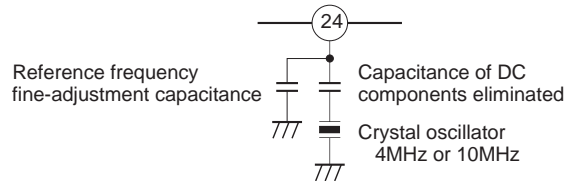
In the same way, when using the 10 MHz crystal oscillator, connecting Pin 3 to GND will select a frequency dividing value of 200 for the reference divider, and the reference frequency will become 50 kHz.

This is summarized in the table below.

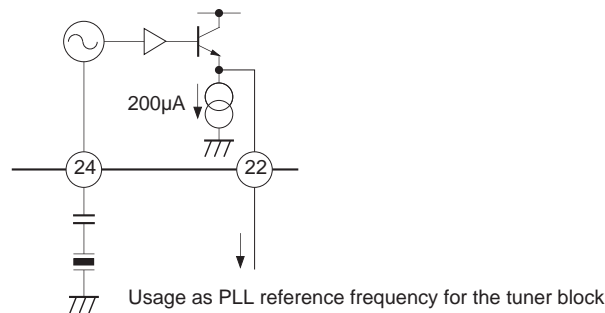
Crystal oscillator	Pin 3 voltage	Frequency dividing value of the reference divider	Reference frequency
4 MHz	Open	80	50 kHz
10 MHz	0.8 V or less	200	50 kHz

Reference oscillator circuit

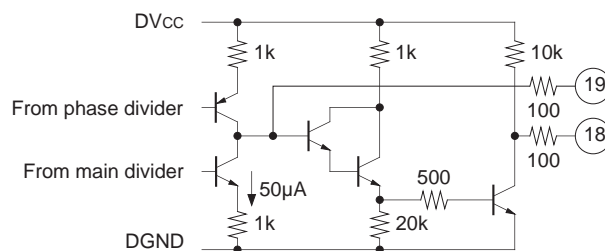
- This is oscillated by connecting a crystal oscillator (4 MHz or 10 MHz) between Pin 24 and GND.
- The input capacitance of Pin 24 is approximately 14 pF. Therefore, a crystal with a load capacitance of 12 pF is recommended. When connecting a crystal with a large load capacitance of 16 pF or so, connect a low capacitance between Pin 24 and GND as shown in the figure below, and adjust the frequency.



- The reference oscillator signal is sent to the reference buffer circuit and output from Pin 22 by the emitter follower.
- The reference oscillator signal becomes the PLL comparison frequency in the IC.
- The output amplitude is approximately 300 mVp-p.



Charge pump circuit



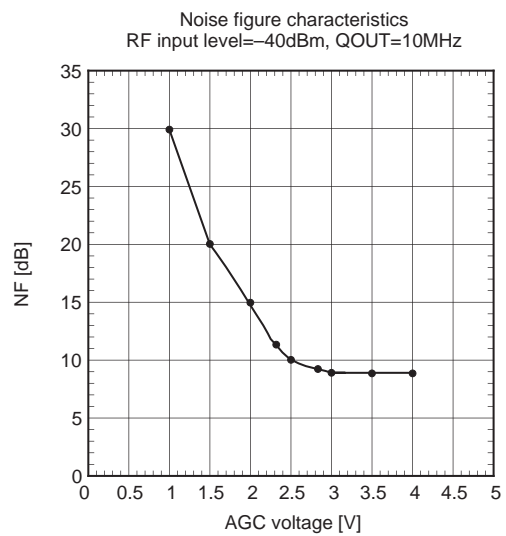
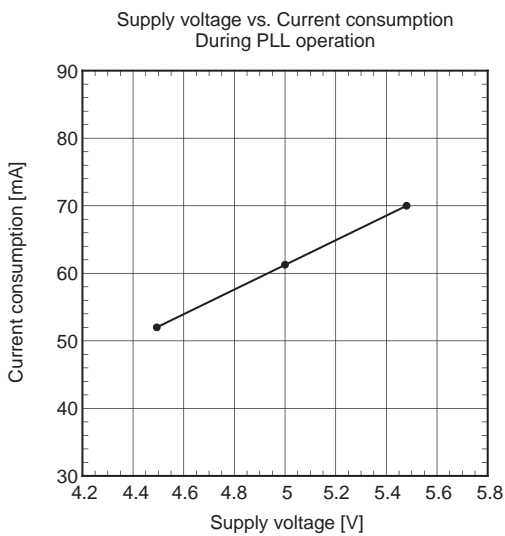
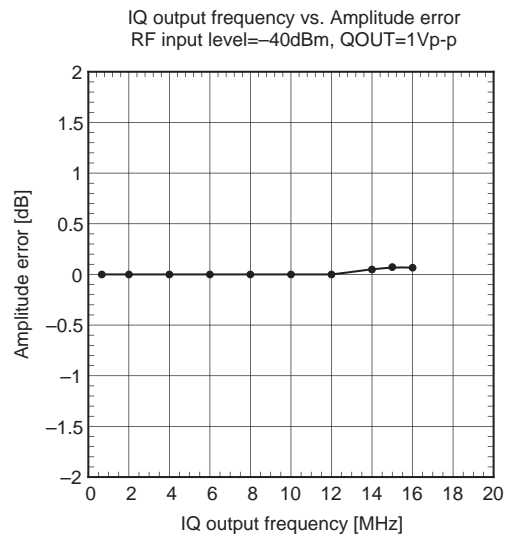
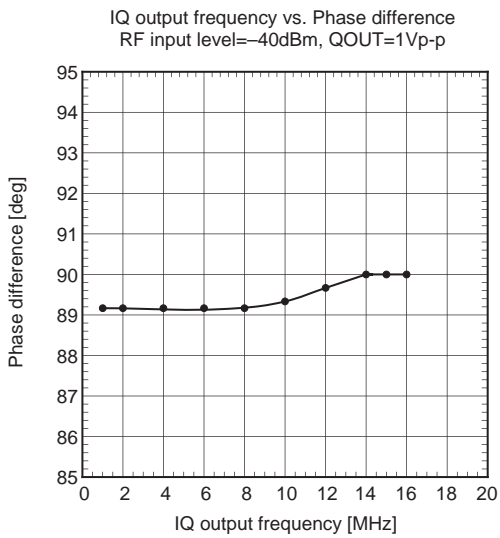
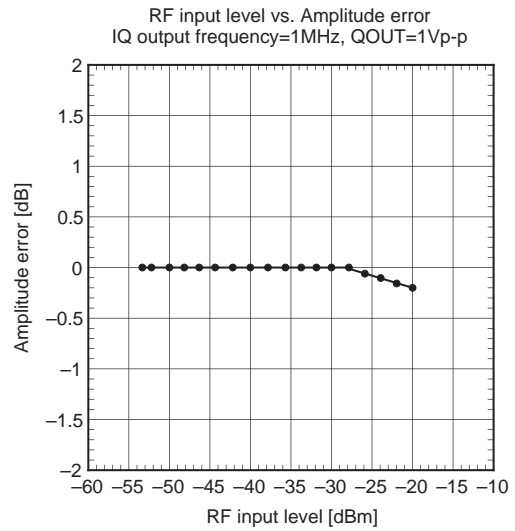
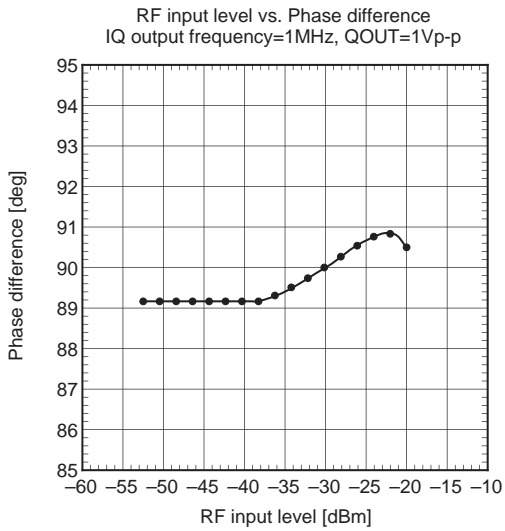
- The output current of the charge pump has been designed at 50 µA.
- The Pin 18 output voltage ranges from approximately 0.3 V to Vcc.
- In the loop filter example for the Electrical Characteristics Measurement Circuit, the lockup time is approximately 25 ms.

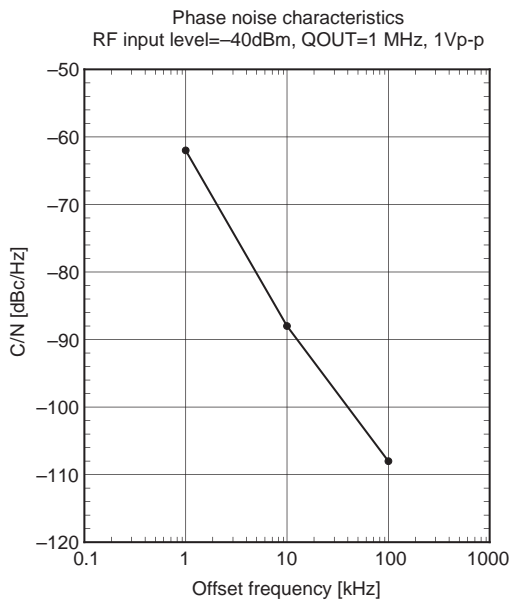
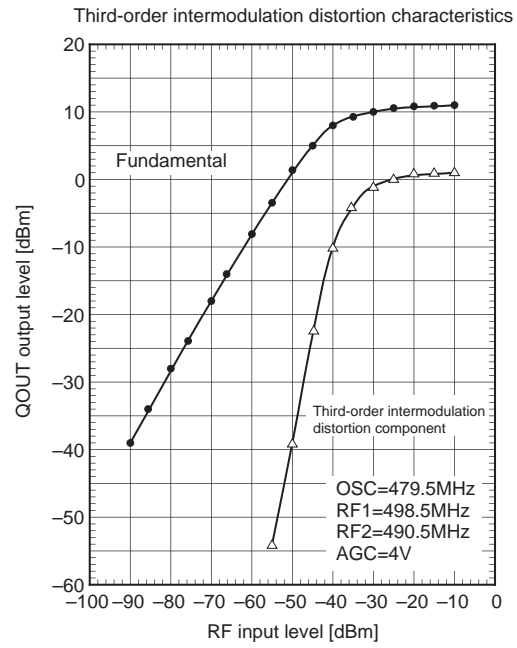
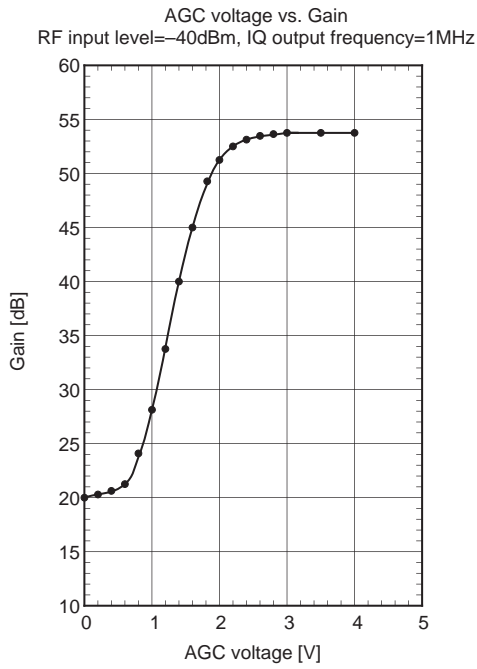
32 frequency division circuit (when Pin 14 is connected to Vcc)

- An oscillation signal is sent from the oscillator circuit to the 32 frequency division circuit via a coupling capacitance. The 32 frequency division signal is output from Pin 13 by the counter.
- The output is approximately 400 mVp-p ECL output.

Notes on Operation

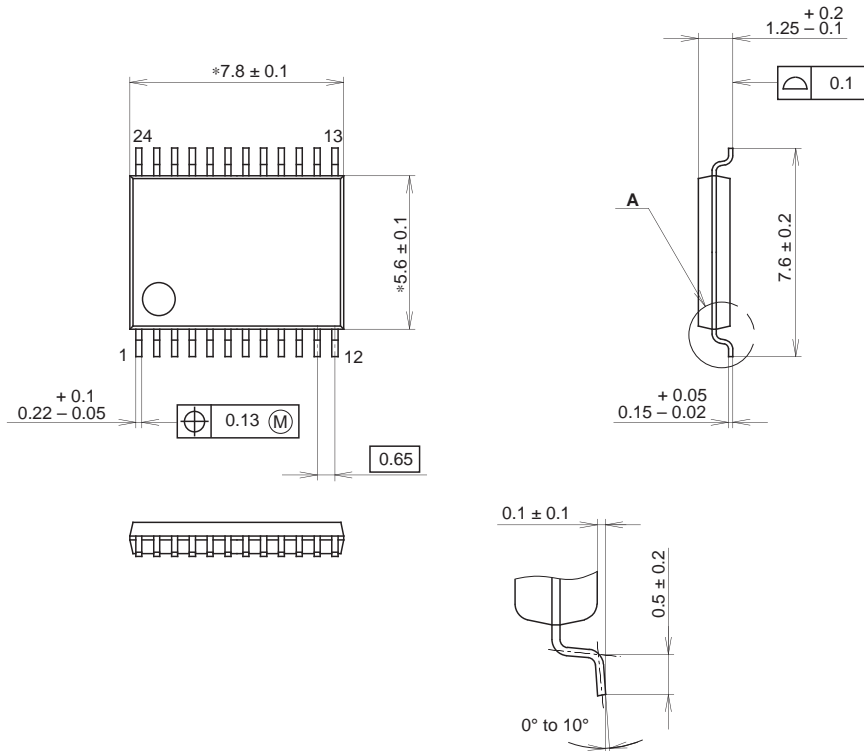
- These circuits use high-frequency processes, and the electrostatic strength is weak. Therefore, please be careful of surges and other excessive input.
- The IQ error may vary depending on the connection locations of the GND pattern and Vcc-GND bypass capacitors, oscillation amplitude of the oscillator circuit, and other factors.





Package Outline Unit : mm

24PIN SSOP(PLASTIC)



DETAIL A

PACKAGE STRUCTURE

SONY CODE	SSOP-24P-L01
EIAJ CODE	SSOP024-P-0056
JEDEC CODE	_____

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER/PALLADIUM PLATING
LEAD MATERIAL	42/COPPER ALLOY
PACKAGE MASS	0.1g

NOTE : PALLADIUM PLATING
 This product uses S-PdPPF (Sony Spec.-Palladium Pre-Plated Lead Frame).